

NEC**SILICON TRANSISTOR**
2SB768**PNP SILICON TRIPLE DIFFUSED TRANSISTOR**
MP-3**DESCRIPTION**

2SB768 is designed for Color TV Vertical Deflection Output, especially in Hybrid Integrated Circuits.

FEATURES

- High Voltage : $V_{CE0} = -150$ V
- Complement to 2SD1033

QUALITY GRADE

Standard

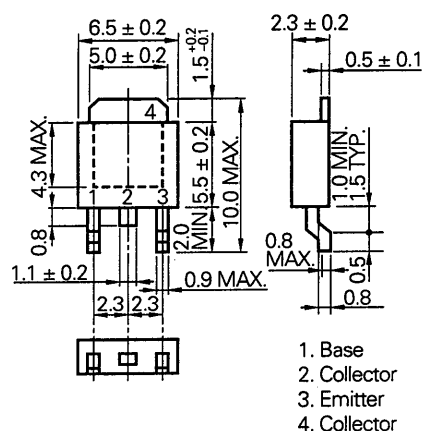
Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS ($T_a = 25$ °C)

Collector to Base Voltage	V_{CBO}	-200	V
Collector to Emitter Voltage	V_{CEO}	-150	V
Emitter to Base Voltage	V_{EBO}	-5	V
Collector Current (DC)	I_C	-2	A
Collector Current (Pulse)*	I_C	-3	A
Total Power Dissipation ($T_a = 25$ °C)**	P_T	2.0	W
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	-55 to +150	°C

* $PW \leq 10$ ms, Duty Cycle ≤ 50 %

** When mounted on ceramic substrate of $7.5 \text{ cm}^2 \times 0.7$ mm

PACKAGE DIMENSIONS
(in millimeters)

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

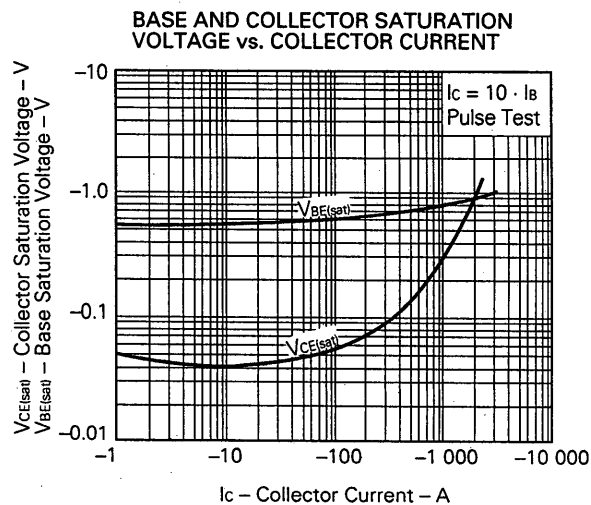
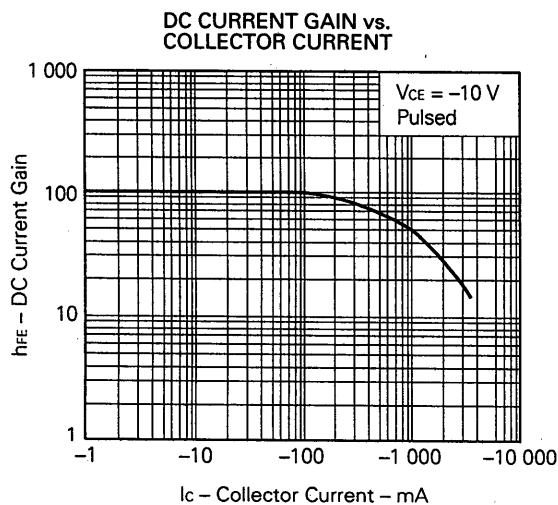
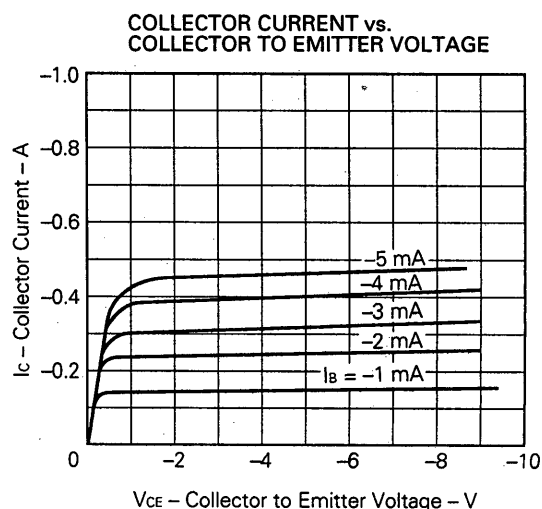
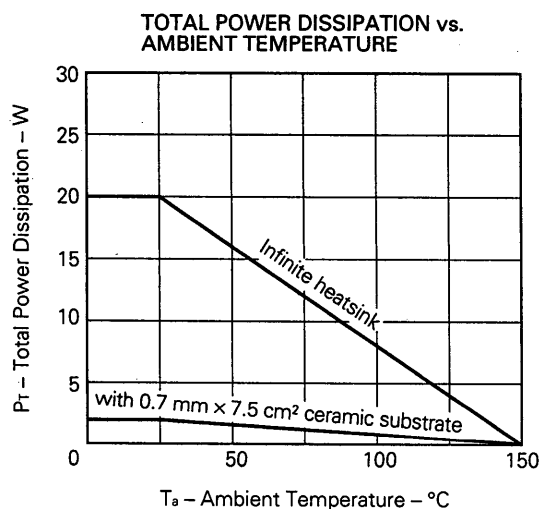
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	I_{CBO}			-50	μA	$V_{CB} = -150\text{ V}, I_E = 0$
Emitter Cutoff Current	I_{EBO}			-50	μA	$V_{EB} = -4.0\text{ V}, I_C = 0$
DC Current Gain	h_{FE1}^{***}	40	80	200		$V_{CE} = -10\text{ V}, I_C = -0.4\text{ A}$
Collector Saturation Voltage	$V_{CE(sat)}^{***}$		-0.15	-1.0	V	$I_C = -500\text{ mA}, I_B = -50\text{ mA}$
Gain Bandwidth Product	f_T		10		MHz	$V_{CE} = -10\text{ V}, I_E = -0.4\text{ mA}$

*** Pulsed: $PW \leq 350\text{ }\mu\text{s}$, Duty Cycle $\leq 2\%$

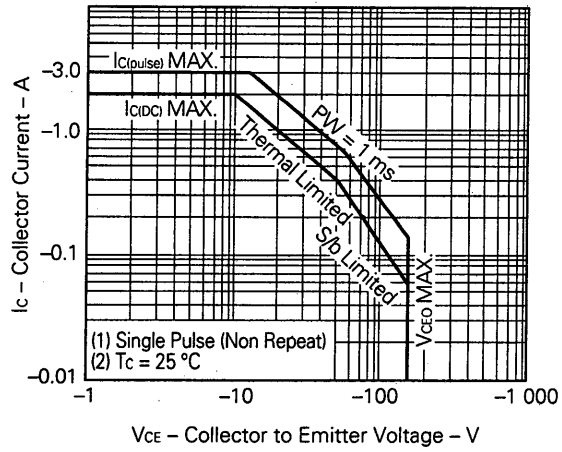
h_{FE} Classification

MARKING	M	L	K
h_{FE1}	40 to 80	60 to 120	100 to 200

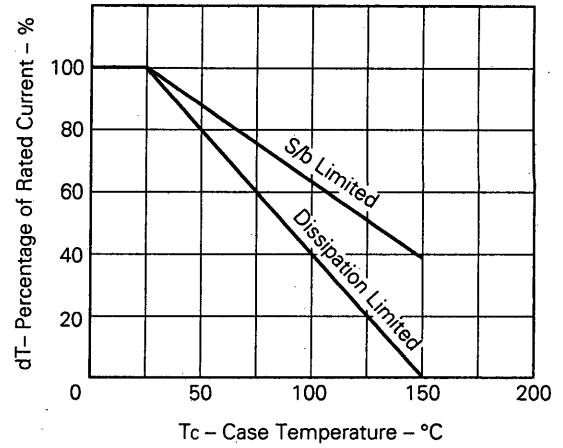
TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)



SAFE OPERATING AREA



DERATING OF SAFE OPERATING AREA



Reference

Application note name	No.
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207
Design of Push-Pull Type Switching Regulators (Basic).	TEB-1002
Design of Push-Pull Type Switching Regulators (Applications).	TEB-1003
Optimum Base Drive Conditions of Switching Power Transistors.	TEB-1014

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The devices listed in this document are not suitable for use in aerospace equipment, submarine cables, nuclear reactor control systems and life support systems. If customers intend to use NEC devices for above applications or they intend to use "Standard" quality grade NEC devices for applications not intended by NEC, please contact our sales people in advance.

Application examples recommended by NEC Corporation.

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.